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Texas Instruments CSD16322Q5

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CSD16322Q5

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SLPS219B-AUGUST 2009-REVISED MAY 2010

N-Channel NexFET[™] Power MOSFET

Check for Samples: CSD16322Q5

FEATURES

- **Optimized for 5V Gate Drive**
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

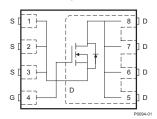
APPLICATIONS

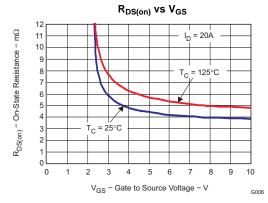
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- Synchronous or Control FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.

Top View





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	25	V	
Q _g	Gate Charge Total (4.5V)	6.8	nC	
Q _{gd}	Gate Charge Gate to Drain	1.3	nC	
		$V_{GS} = 3V$	5.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V$	4.6	mΩ
		V _{GS} = 8V 3.9		mΩ
V _{GS(th)}	Threshold Voltage	1.1	V	

ORDERING INFORMATION

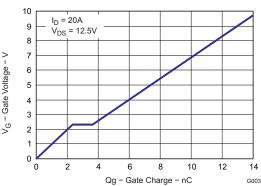
Device	Package	Media	Qty	Ship
CSD16322Q5	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, $T_C = 25^{\circ}C$	97	А
ID	Continuous Drain Current ⁽¹⁾	21	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	136	А
PD	Power Dissipation ⁽¹⁾	3.1	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse I_D = 50A, L = 0.1mH, R_G = 25 Ω	125	mJ

(1) Typical $R_{0JA} = 39^{\circ}C/W$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration ≤300µs, duty cycle ≤2%



GATE CHARGE



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	haracteristics				
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	25		V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$		1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$		100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9 1.1	1.4	V
		$V_{GS} = 3V$, $I_D = 20A$	5.4	7.2	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V, I_{D} = 20A$	4.6	5.8	mΩ
		$V_{GS} = 8V, I_{D} = 20A$	3.9	5	mΩ
9 _{fs}	Transconductance	$V_{DS} = 15V, I_{D} = 20A$	106		S
Dynamic	Characteristics		·		
C _{iss}	Input Capacitance		1050	1365	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V,$ f = 1MHz	740	950	pF
C _{rss}	Reverse Transfer Capacitance		55	70	pF
R _G	Series Gate Resistance		1.1	2.2	Ω
Qg	Gate Charge Total (4.5V)		6.8	9.7	nC
Q _{gd}	Gate Charge Gate to Drain	V _{DS} = 12.5V,	1.3		nC
Q _{gs}	Gate Charge Gate to Source	$I_D = 20A$	2.4		nC
Q _{g(th)}	Gate Charge at Vth		1.3		nC
Q _{oss}	Output Charge	$V_{DS} = 13V, V_{GS} = 0V$	17		nC
t _{d(on)}	Turn On Delay Time		6.1		ns
t _r	Rise Time	V _{DS} = 12.5V, V _{GS} = 4.5V,	10.7		ns
t _{d(off)}	Turn Off Delay Time	$I_D = 20A, R_G = 2\Omega$	12.3		ns
t _f	Fall Time		3.7		ns
Diode C	haracteristics				
V _{SD}	Diode Forward Voltage	$I_{SD} = 20A, V_{GS} = 0V$	0.8	1	V
Q _{rr}	Reverse Recovery Charge	V_{DD} = 13V, I _F = 20A, di/dt = 300A/µs	19		nC
t _{rr}	Reverse Recovery Time	V _{DD} = 13V, I _F = 20A, di/dt = 300A/µs	21		ns

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	MIN	ТҮР	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.4	°C/W
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient ⁽¹⁾ ⁽²⁾			50	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 1.5-inch (1) $^{300}_{3.81}$ -cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{0JC} is specified by design, whereas R_{0JA} is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

(2)



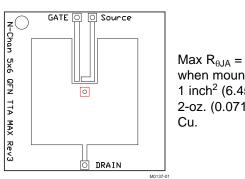
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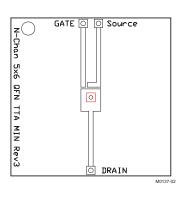
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Max $R_{\theta JA} = 50^{\circ}C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick)



Max $R_{\theta JA} = 123^{\circ}C/W$ when mounted on minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

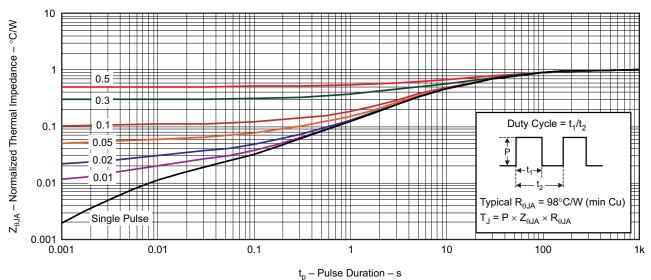


Figure 1. Transient Thermal Impedance

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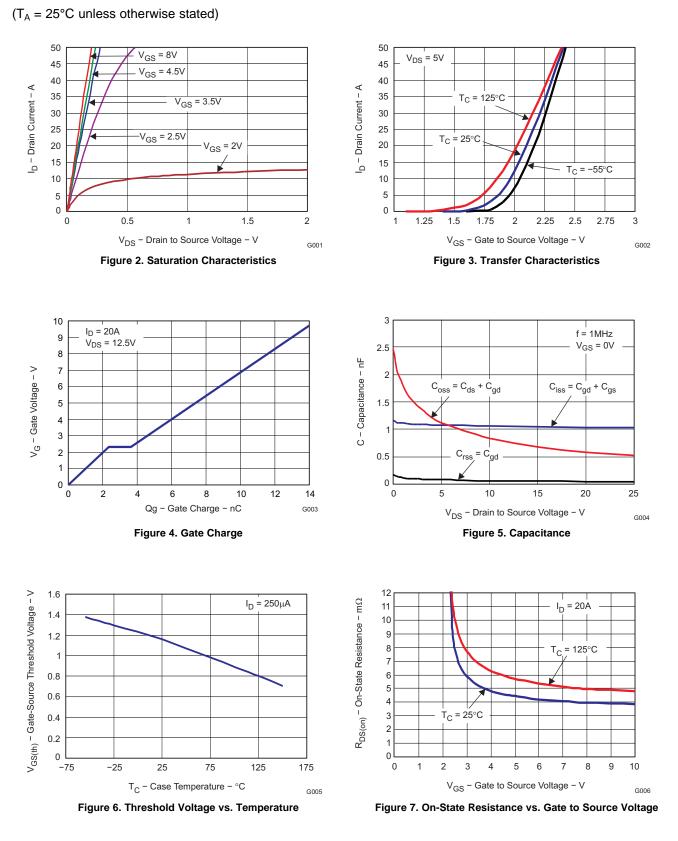
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V INSTRUMENTS

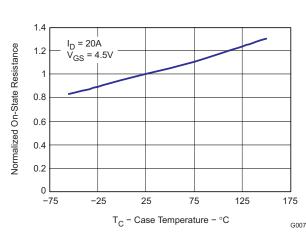
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

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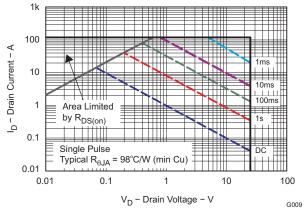


Figure 10. Maximum Safe Operating Area

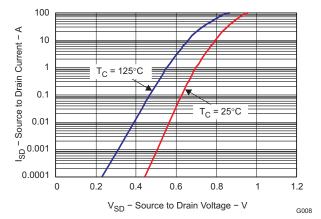


Figure 9. Typical Diode Forward Voltage

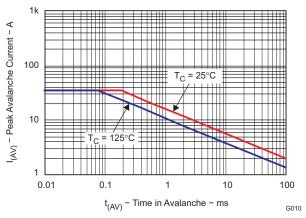
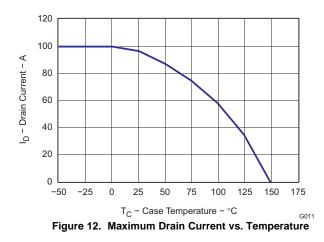


Figure 11. Single Pulse Unclamped Inductive Switching



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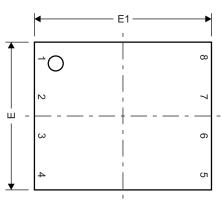
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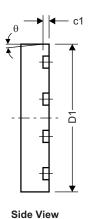
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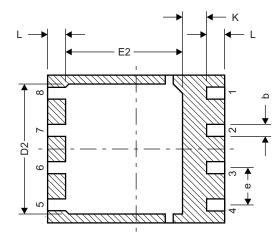
MECHANICAL DATA

Q5 Package Dimensions

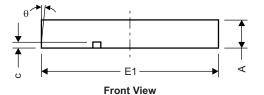








Bottom View



M0140-01

DIM	MILLIN	METERS	INC	HES
DIM	MIN	MAX	MIN	МАХ
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
С	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
е	1.27	' TYP	0.0	50
К	0.760		0.030	
L	0.510	0.710	0.020	0.028
θ	0.00			



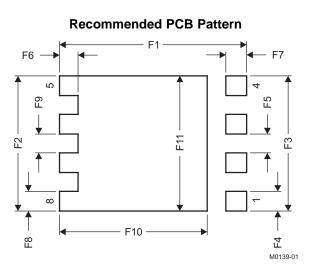
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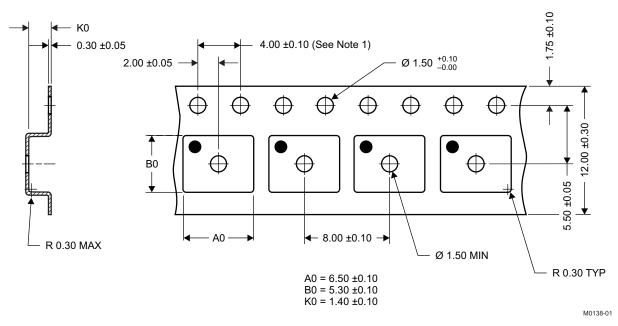
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DIM	MILLIM	IETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5 Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket
- 6. MSL1 260°C (IR and convection) PbF reflow compatible



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REVISION HISTORY

Changes from Original (August 2009) to Revision A Page • Changed Note1 of the ABSOLUTE MAXIMUM RATINGS From: R_{0JA} = 39°C/W To: Typical R_{0JA} = 39°C/W To: Typical R_{0JA} = 98°C/W 1 • Changed Figure 1 text From: R_{0JA} = 99°C/W To: Typical R_{0JA} = 98°C/W 3 • Changed Figure 10 text From: R_{0JA} = 99°C/W To: Typical R_{0JA} = 98°C/W 5 • Changed Figure 11 X- axis values 5 Changes from Revision A (April 2010) to Revision B Page

•	Changed $R_{DS(on)}$ - V_{GS} = 3V in the Electrical Characteristics table From: 7 To: 7.2 in the max column	2
•	Deleted the Package Marking Information section	7



PACKAGE OPTION ADDENDUM

7-Jan-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD16322Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16322	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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Addendum-Page 1



7-Jan-2016

Addendum-Page 2



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